

STSA851

Low voltage fast-switching NPN power transistor

Features

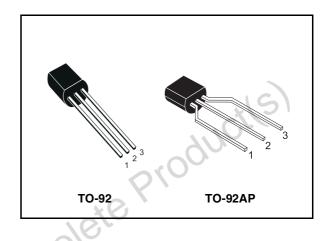
- Very low collector to emitter saturation voltage
- High current gain characteristic
- Fast-switching speed

Applications

- Emergency lighting
- Voltage regulators
- Relay drivers
- High efficiency low voltage switching applications

Description

The device is manufactured in NPN planar technology by using a "base island" layout. the resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.



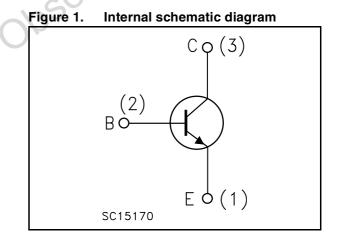


Table 1.	Device summary
	Borroo caninary

Order code	ode Marking Package		Packaging
STSA851	SA851	TO-92	Bulk
STSA851-AP	SA851	TO-92AP	Ammopack

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	duct(s)
	* Proc
-10S	plete
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Electrical ratings 1

Table 2. Absolute maximum rat	ing
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Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	150	V
V_{CEO}	Collector-emitter voltage $(I_B = 0)$	60	V
V_{EBO}	Emitter-base voltage (I _C = 0)	7	V
۱ _C	Collector current	5	А
I _{CM}	Collector peak current (t _P < 5 ms)	20	А
Ι _Β	Base current	1,6	А
P _{tot}	Total dissipation at T _{amb} = 25 °C		W
T _{stg}	Storage temperature	-65 to 150	°C
Т _Ј	Max. operating junction temperature	150	°C

Table 3. Thermal data

	ТЈ	Max. operating junction temperature 150		150	°C
	Table 3.	Thermal data	<u> </u>		
	Symbol	Parameter		Value	Unit
	R _{thj-amb}	Thermal resistance junction-ambient	max	114	°C/W
obsole	ste P	roducilsi			

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2 Electrical characteristics

(T_{case} = 25 °C unless otherwise specified)

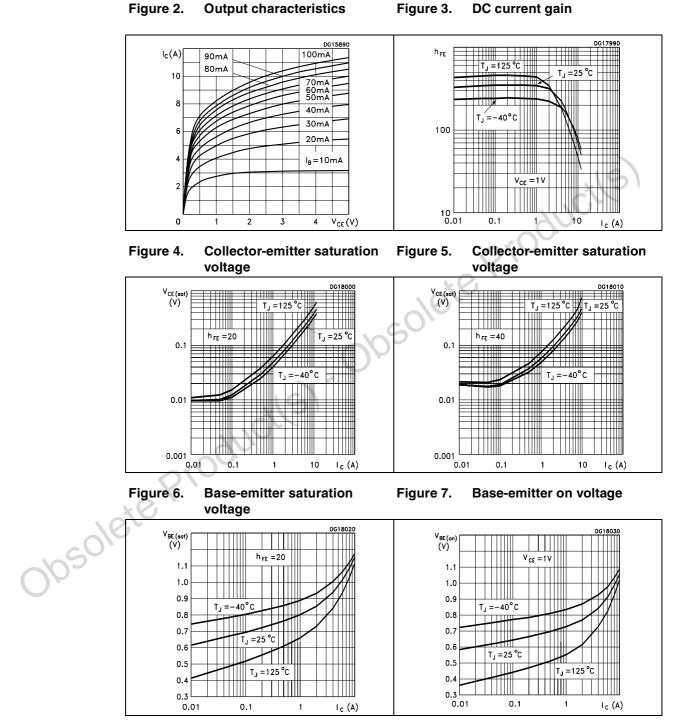
	Table 4.	Electrical characteristics						
	Symbol	Parameter	Test co	nditions	Min.	Тур.	Max.	Unit
	I _{CBO}	Collector cut-off current	V _{CB} = 120 V				50	nA
	1CBO	(I _E = 0)	V _{CB} = 120 V	T _C = 100 °C			1	μA
	I _{EBO}	Emitter cut-off current $(I_{\rm C} = 0)$	V _{EB} = 7 V				10	nA
	V _{(BR)CBO} ⁽¹⁾	Collector-base breakdown Voltage (I _E = 0)	I _C = 100 μA		150	JU	J.C.	v
	V _{(BR)CEO} ⁽¹⁾	Collector-emitter breakdown Voltage (I _B = 0)	I _C = 10 mA	×eF	60			V
	V _{(BR)EBO} ⁽¹⁾	Emitter-base breakdown Voltage $(I_{\rm C}=0)$	I _E = 100 μA	plere	7			V
			l _C = 100 mA	I _B = 5 mA		10	50	mV
	V _{CE(sat)} ⁽¹⁾	Collector-emitter	I _C = 1 A	I _B = 50 mA		70	120	mV
	0=(041)	saturation voltage	I _C = 2 A	I _B = 50 mA		140	200	mV
		C.L.	I _C = 5 A	I _B = 200 mA		320	450	mV
	V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = 4 A	I _B = 200 mA		1	1.15	V
	0		l _C = 10 mA	V _{CE} = 1 V	150	300		
		DC ourrent agin	I _C = 2 A	$V_{CE} = 1 V$	150	270	350	
C	hFE	DC current gain	I _C = 5 A	$V_{CE} = 1 V$	90	140		
//ĸ			I _C = 10 A	$V_{CE} = 1 V$	30	50		
	f _T	Transition frequency	V _{CE} = 10 V	l _C = 100 mA		130		MHz
016	C _{CBO}	Collector-base capacitance	V _{CB} = 10 V	f = 1 MHz		45		pF
		Resistive load						
	t _{on}	Turn-on time	I _C = 1 A	•••		55		ns
	t _s	Storage time	$I_{B1} = -I_{B2} = 0.7$	1 A		1.35		μs
	t _f	Fall time				120		ns

Table 4. Electrical characteristics

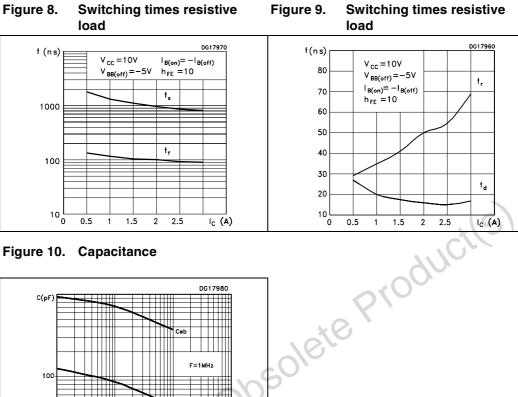
1. Pulsed duration = 300 μ s, duty cycle \ge 1.5%.

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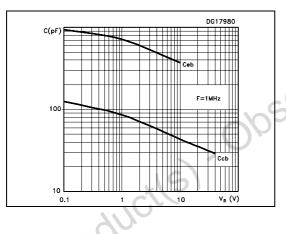
2.1 Electrical characteristics (curves)



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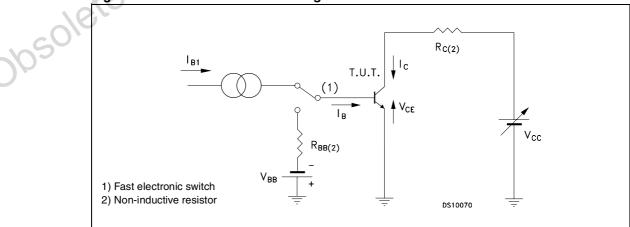






2.2 **Test circuit**

Figure 11. Resistive load switching test circuit



3 Package mechanical data

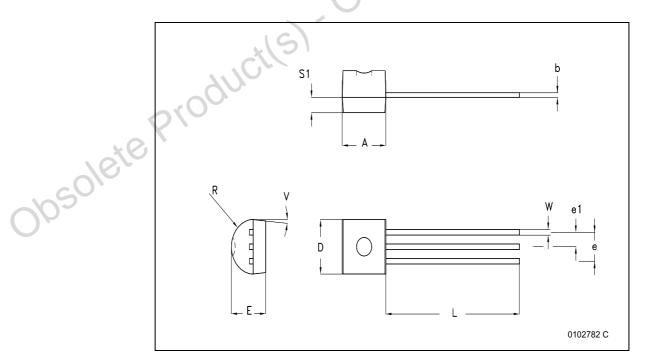
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Obsolete Product(s). Obsolete Product(s)

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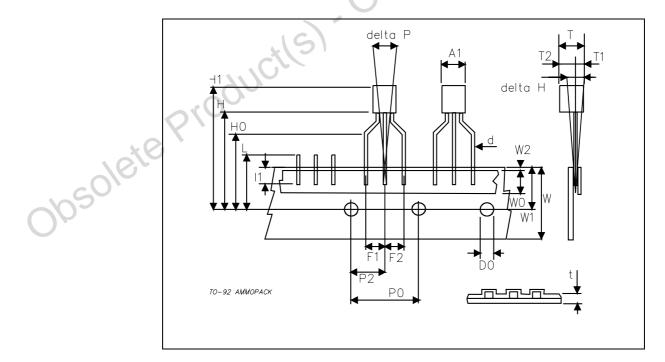
DIM.	mm.			
	MIN.	ТҮР	MAX.	
A	4.32		4.95	
b	0.36		0.51	
D	4.45		4.95	
E	3.30		3.94	
е	2.41		2.67	
e1	1.14		1.40	
L	12.70	0	15.49	
R	2.16	.0.	2.41	
S1	0.92	1610	1.52	
W	0.41	<u> </u>	0.56	
V		5 ⁰		







DIM.	mm.				
DIM.	MIN.	TYP	MAX.		
A1			4.80		
Т			3.80		
T1			1.60		
T2			2.30		
d			0.48		
P0	12.50	12.70	12.90		
P2	5.65	6.35	7.05		
F1,F2	2.44	2.54	2.94		
delta H	-2.00		2.00		
W	17.50	18.00	19.00		
W0	5.70	6.00	6.30		
W1	8.50	9.00	9.25		
W2			0.50		
Н	18.50		20.50		
H0	15.50	16.00	16.50		
H1			25.00		
D0	3.80	4.00	4.20		
t			0.90		
L			11.00		
11	3.00				
delta P	-1.00		1.00		



TO-92 AMMOPACK SHIPMENT (Suffix"-AP") MECHANICAL DATA

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4 Revision history

Table 5.Document revision history

Date	Revision	Changes
05-Sep-2003	2	
25-Mar-2008	3	New graphics.

obsolete Product(s)-Obsolete Product(s)

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